

# PRODUCT SPECIFICATION

**Model No.: FYS-8012CUB-11-DW**

Descriptions:
<ul style="list-style-type: none"> <li>■ 0.80 Inch Single Digit Display</li> <li>■ Common Cathode</li> <li>■ Emitting Color : Ultra Blue</li> <li>■ Chip Material:InGaN</li> <li>■ Black Face</li> <li>■ White Segment</li> </ul>



CUSTOMER APPROVED SIGNATURES	APPROVED BY	CHECKED BY	PREPARED BY

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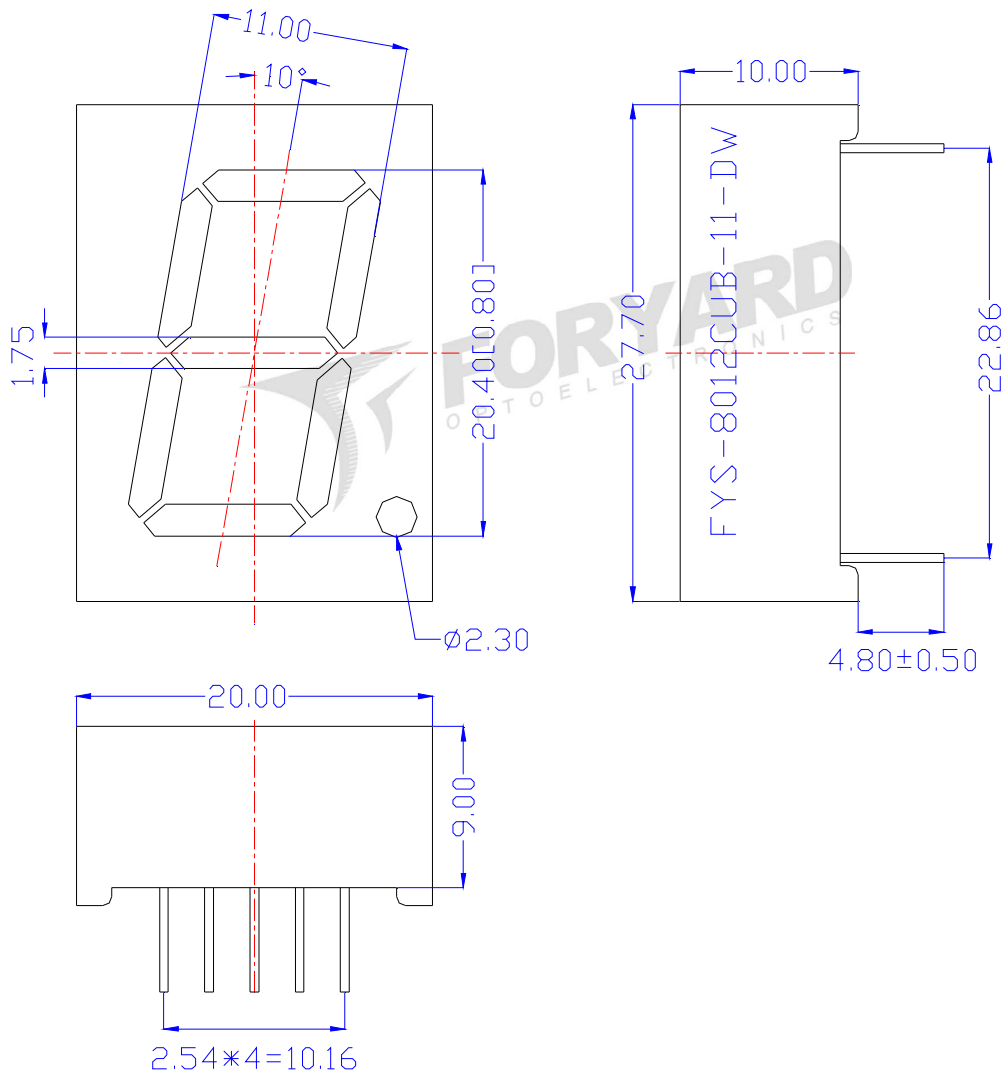
**Http://www.foryard.com**

**Model No.: FYS-8012CUB-11-DW**

**Features -**

1. 0.80 inch (20.40mm) digit height.
2. Case mold type.
3. RoHS compliant.
4. Low current operation
5. Low power consumption.
6. Easy mounting on P.C. board or socket.

**Mechanical Dimensions -**

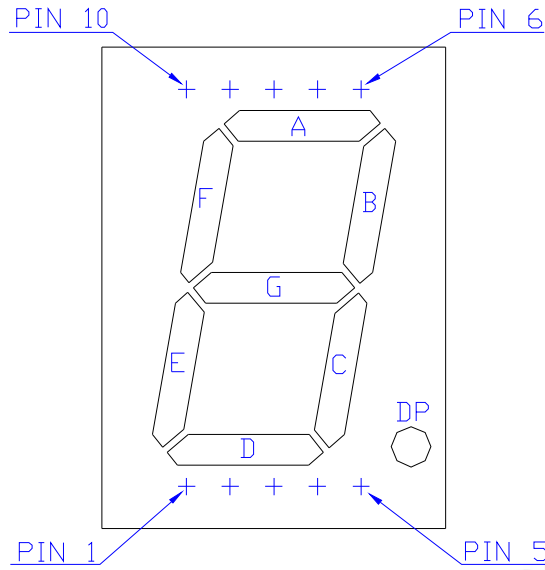


**Notes:**

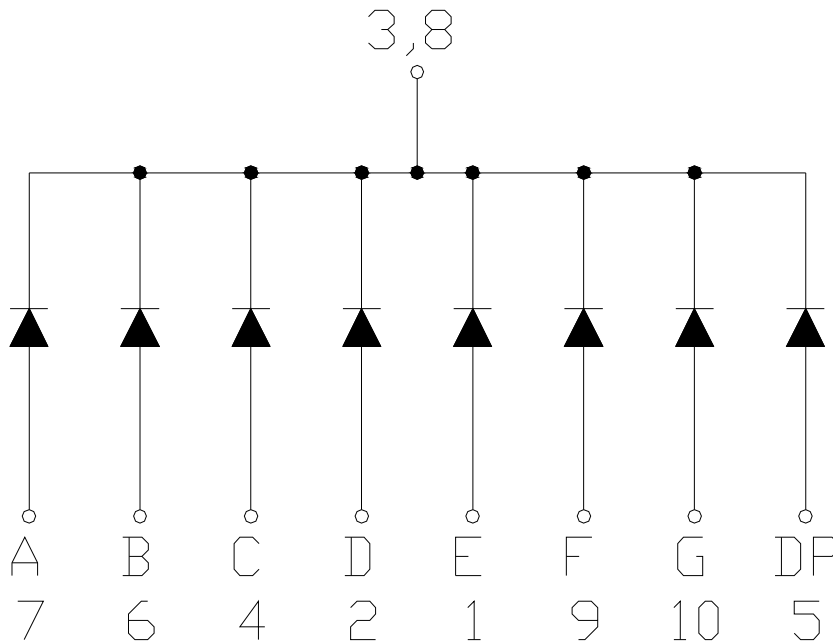
1. All pins are  $\phi 0.50$  [0.020] mm
2. Dimension in millimeter [inch], tolerance is  $\pm 0.25$  [0.010] and angle is  $\pm 1^\circ$  unless otherwise noted.
3. Bending  $\leq$  Length \* 1%.
4. The specifications, characteristics and technical data described in the datasheet are subject to change without prior notice.

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**■ All Light On Segments Feature & Pin Position**



**■ Internal Circuit Diagrams -**



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**■ Absolute maximum ratings**

(Ta=25°C)

Parameter	Symbol	Test Condition	Value		Unit
			Min	Max	
Reverse Voltage	VR	IR=30	5	—	V
Forward Current	IF	—	—	30	mA
Power Dissipation	Pd	—	—	100	mW
Pulse Current	Ipeak	Duty=0.1mS,1KHz	—	150	mA
Operating Temperature	Topr	—	-40	+85	°C
Storage Temperature	Tstr	—	-40	+85	°C

**■ Electrical-Optical Characteristics**

● Color Code & Chip Characteristics:(Test Condition:IF=20mA)

(Ta=25°C)

Emitting Color		Dice Material	Peak Wave Length( $\lambda_p$ )	Spectral Line halfwidth h( $\Delta\lambda_{1/2}$ )	Forward Voltage(VF)		Luminous Intensity (Iv) Unit:mcd
					Typ	Max	
UB	Ultra Blue	InGaN	470nm	30nm	2.80	3.80	80~90
Segment-to-Segment Luminous Intensity ratio(Iv-M)						1.5:1	

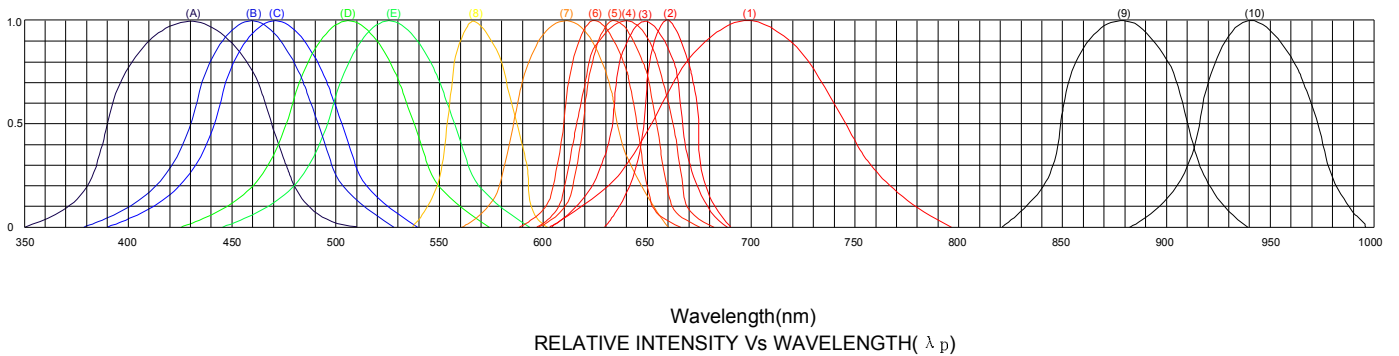
Note:

- 1.Luminous Intensity is based on the Foryard standards.
- 2.Pay attention about static for InGaN

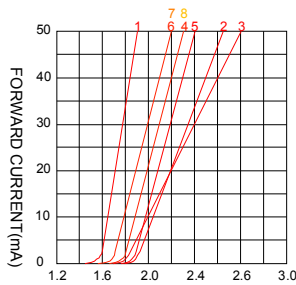
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**Typical Electrical / Optical Characteristics Curves**

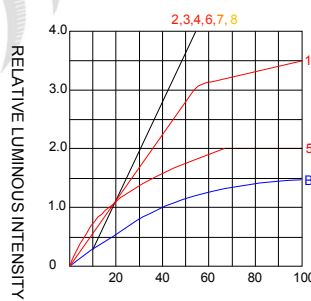
(Ta = 25°C Unless Otherwise Noted)



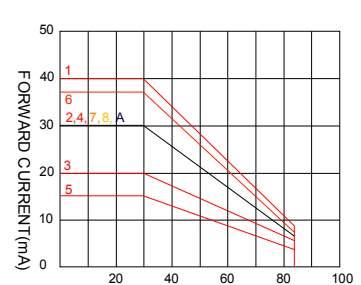
- (1)-GaP 700nm/Red
- (2)-AlGaAs/SH 660nm/Hi Red
- (3)-AlGaAs/DH 650nm/Super Red
- (4)-AlGaInP/640nm/Ultra Hi Red
- (5)-AlGaInP/635nm/Ultra Red
- (6)-GaAlP/AlGaInP/625nm/Orange
- (7)-GaAsP/AlGaInP 610nm/Amber
- (8)-GaP 570nm/Yellow Green
- (9)-GaAlAs 880nm
- (10)-GaAs/GaAs & GaAlAs/GaAs 940nm
- (A)-GaN/SiC 430nm/Blue
- (B)-InGaN/SiC 460nm/Blue
- (C)-InGaN/SiC 470nm/Blue
- (D)-InGaN/SiC 505nm/Ultra Green
- (E)-InGaN/SiC 525nm/Ultra Green



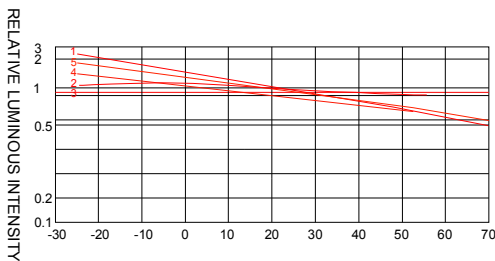
**FORWARD VOLTAGE(Vf)**  
FORWARD CURRENT VS.  
FORWARD VOLTAGE



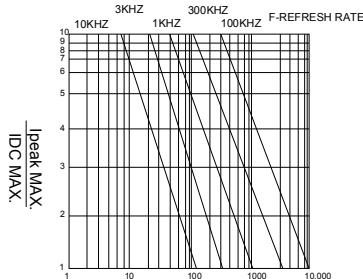
**FORWARD CURRENT (mA)**  
RELATIVE LUMINOUS  
INTENSITY VS FORWARD  
CURRENT



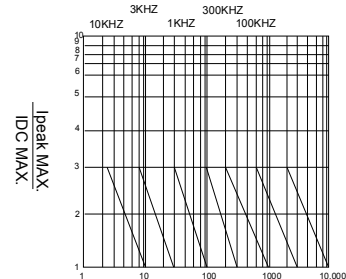
**AMBIENT TEMPERATURE Ta(°C)**  
FORWARD CURRENT VS. AMBIENT  
TEMPERATURE



**AMBIENT TEMPERATURE Ta(°C)**



**tp-PULSE DURATION  $\mu$ S**  
(1,2,3,4,6,8,B,D,J,K)



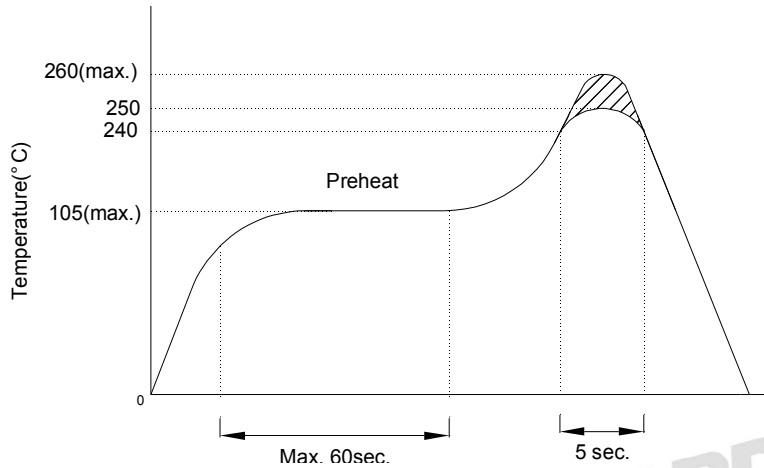
**tp-PULSE DURATION  $\mu$ S**  
(5)

NOTE: 25°C free air temperature unless otherwise specified

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■ **Precautions For Use -**

**1. Recommended Soldering conditions-Wave Soldering**



**2. Soldering Iron**

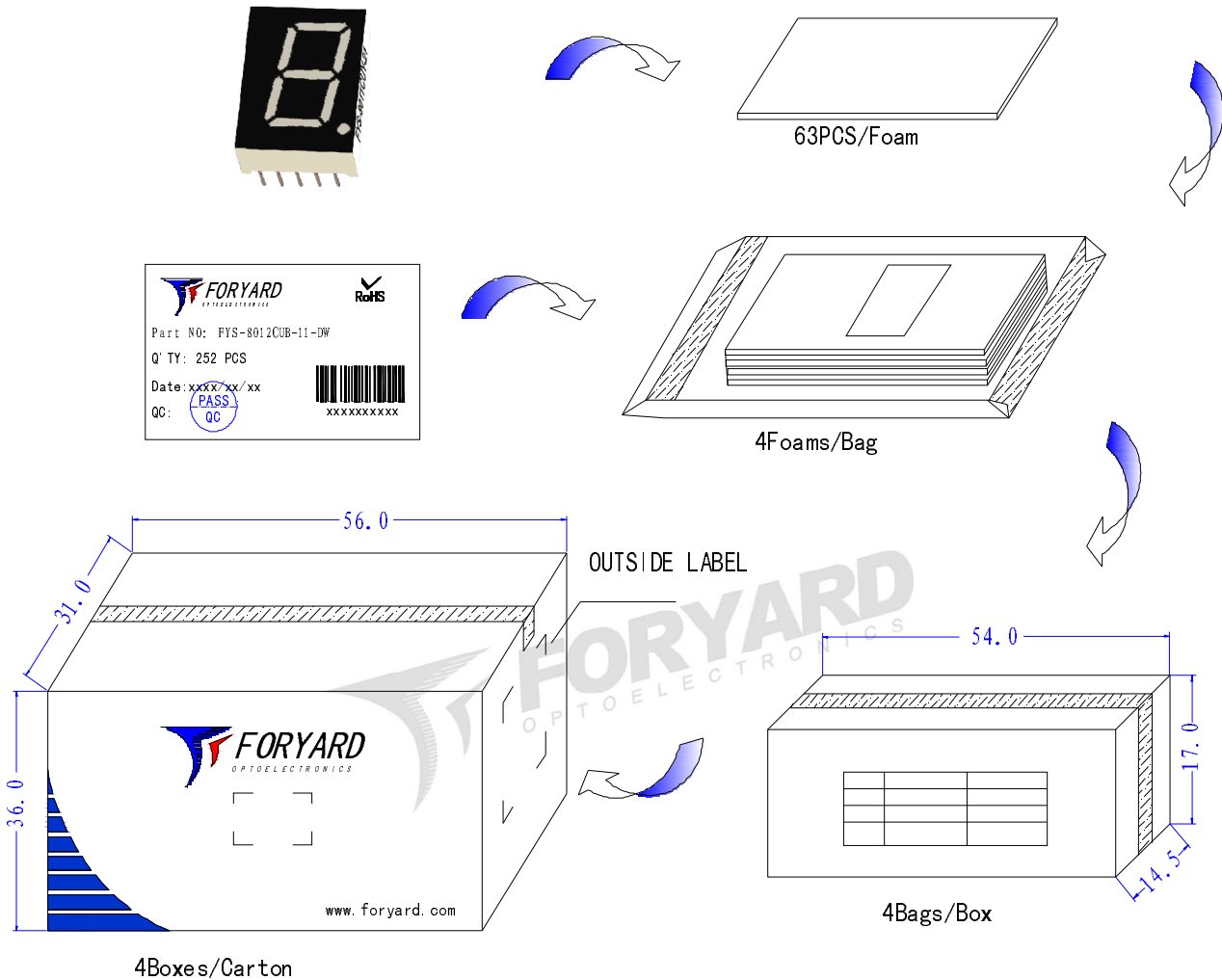
Basic SPEC. is  $\leq 5$ sec. When  $260^{\circ}\text{C}$ . If temperature is higher, time should be shorter ( $+10^{\circ}\text{C} \rightarrow -1$ sec.).

Power dissipation of iron should be smaller than 15W, and temperature should be controllable.

Surface temperature of the device should be under  $230^{\circ}\text{C}$ .

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**■ Packing Diagram**



OUTSIDE LABEL

Note: The specifications are subject to change without notice. Please contact us for updated information.